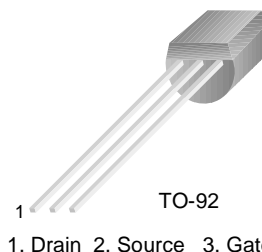


PF5102

N-Channel Switch

- This device is designed for low level analog switching, sample and hold circuits and chopper stabized amplifiers.
- Sourced from process 51.
- See J111 for characteristics.



Absolute Maximum Ratings * $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	40	V
V_{GS}	Gate-Source Voltage	-40	V
I_{GF}	Forward Gate Current	50	A
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1. These ratings are based on a maximum junction temperature of 150 degrees C.
2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)GSS}$	Gate-Source Breakdwon Voltage	$I_C = -1.0\mu\text{A}, V_{DS} = 0$	-40		V
I_{GSS}	Gate Reverse Current	$V_{GS} = -15\text{V}, V_{DS} = 0$ $V_{GS} = -15\text{V}, V_{DS} = 0, T_A = 125^\circ\text{C}$		-1.0 -0.2	nA μA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 15\text{V}, I_D = 1.0\text{nA}$	-0.7	-1.6	V
$V_{GS(f)}$	Gate-Source Forward Voltage	$I_G = 1.0\text{mA}, V_{DS} = 0$		1.0	
On Characteristics					
I_{DSS}	Zero-Gate Voltage Drain Current *	$V_{DS} = 15\text{V}, V_{GS} = 0$	4.0	20	nA
Small Signal Characteristics					
g_{fs}	Forward Transfer Conductance	$V_{DS} = 15\text{V}, V_{GS} = 0, f = 1.0\text{KHz}$	11,000		μmhos
g_{oss}	Output Conductance	$V_{DS} = 15\text{V}, I_D = 500\mu\text{A}, f = 1.0\text{KHz}$		25	μmhos
C_{iss}	Input Capacitance	$V_{DG} = 15\text{V}, V_{GS} = 0, f = 1.0\text{MHz}$		16	pF
C_{rss}	Reverse Transfer Capacitance	$V_{DG} = 15\text{V}, V_{GS} = 0, f = 1.0\text{MHz}$		6	pF

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1.0\%$

Thermal Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	$^\circ\text{C/W}$

Package Dimensions

TO-92



Dimensions in Millimeters

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